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Kind regards,

Team Nexperia



**Product data sheet** 

# 1. Product profile

#### 1.1 General description

PNP general-purpose double transistors in a small SOT143B Surface-Mounted Device (SMD) plastic package.

#### Table 1.Product overview

Type number	Package		NPN complement
	NXP	JEITA	
BCV62	SOT143B	-	BCV61
BCV62A			BCV61A
BCV62B			BCV61B
BCV62C			BCV61C

#### 1.2 Features and benefits

- Low current (max. 100 mA)
- Low voltage (max. 30 V)
- Matched pairs
- AEC-Q101 qualified
- Small SMD plastic package

#### **1.3 Applications**

- Applications with working point independent of temperature
- Current mirrors

#### 1.4 Quick reference data

# Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	istor					
$V_{\text{CEO}}$	collector-emitter voltage	open base	-	-	-30	V
I <sub>C</sub>	collector current		-	-	-100	mA
Transisto	r TR1					
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -100 \mu\text{A}$	100	-	-	
		$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -2 \text{ mA}$	100	-	800	



#### PNP general-purpose double transistors

Table 2.	le 2. Quick reference data continued					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Transisto	r TR2					
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -2 \text{ mA}$				
	BCV62		100	-	800	
	BCV62A		100	-	250	
	BCV62B		220	-	475	
	BCV62C		420	-	800	

### 2. Pinning information

Table 3.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	collector TR2; base TR1 and TR2	4 3	4 3
2	collector TR1		
3	emitter TR1		TR2
4	emitter TR2		1 2 006aaa843

### 3. Ordering information

Type number	Package	Package					
	Name	Description	Version				
BCV62	-	plastic surface-mounted package; 4 leads	SOT143B				
BCV62A							
BCV62B							
BCV62C							

### 4. Marking

Table 5. Marking codes	
Type number	Marking code <sup>[1]</sup>
BCV62	3M*
BCV62A	3J*
BCV62B	3К*
BCV62C	3L*

[1] \* = -: made in Hong Kong

\* = p: made in Hong Kong

\* = t: made in Malaysia

\* = W: made in China

# 5. Limiting values

Symbol	Parameter	Conditions	Min	Мах	Unit
Per trans	istor				
V <sub>CBO</sub>	collector-base voltage	open emitter	-	-30	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-30	V
V <sub>EBS</sub>	emitter-base voltage	$V_{CE} = 0 V$	-	-6	V
l <sub>C</sub>	collector current		-	-100	mA
I <sub>CM</sub>	peak collector current		-	-200	mA
I <sub>BM</sub>	peak base current		-	-200	mA
Per devic	e				
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	<u>[1]</u> -	250	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB).

# 6. Thermal characteristics

Table 7.	Thermal characteristics						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1] -	-	500	K/W	

[1] Device mounted on an FR4 PCB.

## 7. Characteristics

#### Table 8.Characteristics

 $T_j = 25$  °C unless otherwise specified.

,								
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit		
Transistor TR1								
I <sub>CBO</sub>	collector-base	$V_{CB} = -30 \text{ V}; \text{ I}_{\text{E}} = 0 \text{ A}$	-	-	-15	nA		
	cut-off current	$\label{eq:VCB} \begin{array}{l} V_{CB} = -30 \ \text{V}; \ \text{I}_{\text{E}} = 0 \ \text{A}; \\ T_{j} = 150 \ ^{\circ}\text{C} \end{array}$	-	-	-5	μ <b>A</b>		
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	-100	nA		
h <sub>FE</sub>	DC current gain	$\begin{array}{l} V_{CE}=-5 \ V; \\ I_{C}=-100 \ \mu A \end{array}$	100	-	-			
		$V_{CE} = -5 \text{ V}; I_C = -2 \text{ mA}$	100	-	800			
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = -10 mA; I <sub>B</sub> = -0.5 mA	-	-75	-300	mV		
		$I_{\rm C}$ = -100 mA; $I_{\rm B}$ = -5 mA	-	-250	-650	mV		

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_{C} = -10 \text{ mA};$ $I_{B} = -0.5 \text{ mA}$	[1]	-	-700	-	mV
		$I_{C} = -100 \text{ mA};$ $I_{B} = -5 \text{ mA}$	<u>[1]</u>	-	-850	-	mV
V <sub>BE</sub>	base-emitter voltage	$I_C = -2 \text{ mA}; V_{CE} = -5 \text{ V}$	[2]	-600	-650	-750	mV
		$I_C = -10 \text{ mA};  V_{CE} = -5  V$	[2]	-	-	-820	mV
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -10 mA; f = 100 MHz		100	-	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 \text{ V};$ $I_E = i_e = 0 \text{ A}$		-	4.5	-	pF
NF	noise figure	$ \begin{array}{l} V_{CE} = -5 \ V; \\ I_{C} = -200 \ \mu A; R_{S} = 2 \ k \Omega; \\ f = 1 \ k Hz; B = 200 \ Hz \end{array} $		-	-	10	dB
Transisto	r TR2						
V <sub>EBS</sub>	emitter-base voltage	$V_{CB}=0~V;~I_{E}=-250~mA$		-	-	-1.5	V
		$V_{CB}$ = 0 V; I <sub>E</sub> = -10 $\mu$ A		-400	-	-	mV
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -2 \text{ mA}$					
	BCV62			100	-	800	
	BCV62A			100	-	250	
	BCV62B			220	-	475	
	BCV62C			420	-	800	
Transisto	rs TR1 and TR2						
$I_{C1}/I_{E2}$	current matching	I <sub>E2</sub> = -0.5 mA; V <sub>CE1</sub> = -5 V;					
		$T_{amb} \le 25 \ ^{\circ}C$		0.7	-	1.3	
		$T_{amb} \le 150 \ ^{\circ}C$		0.7	-	1.3	
I <sub>E2</sub>	emitter current 2	$V_{CE1} = -5 V$	[3]	-	_	-5	mA

# **Table 8.** Characteristics ... continued $T_i = 25$ °C unless otherwise specified.

[1]  $V_{BEsat}$  decreases by about 1.7 mV/K with increasing temperature.

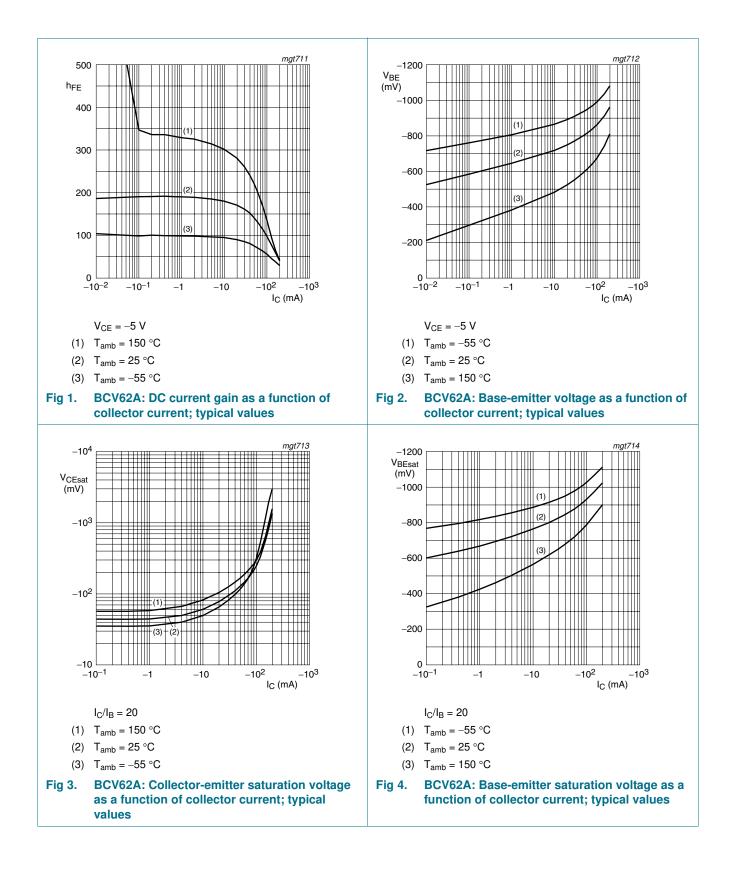
[2]  $V_{BE}$  decreases by about 2 mV/K with increasing temperature.

[3] Device, without emitter resistors, mounted on an FR4 PCB.

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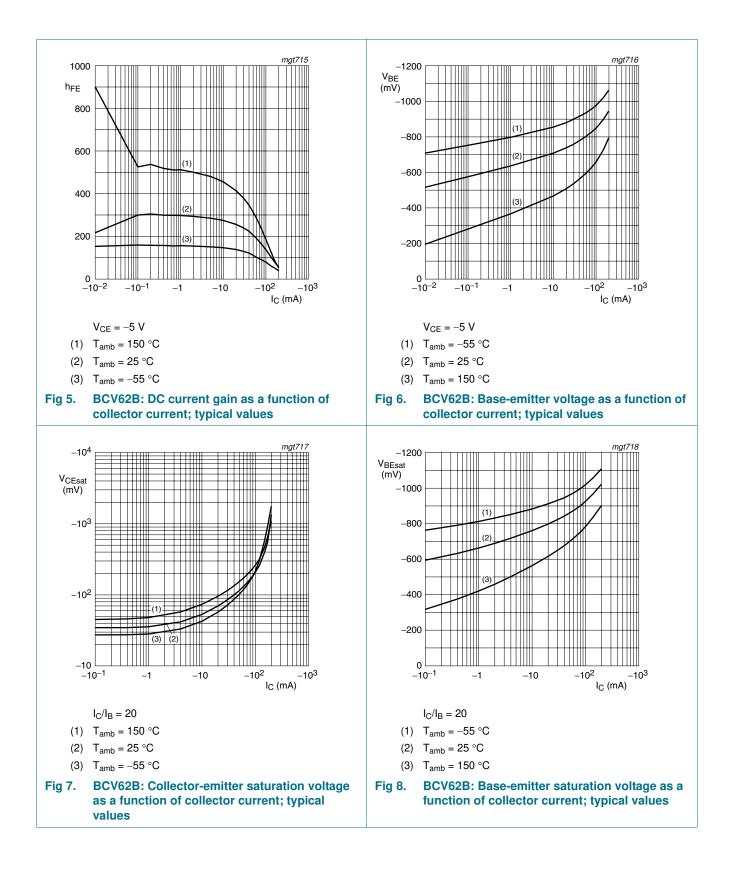
#### PNP general-purpose double transistors

**BCV62** 

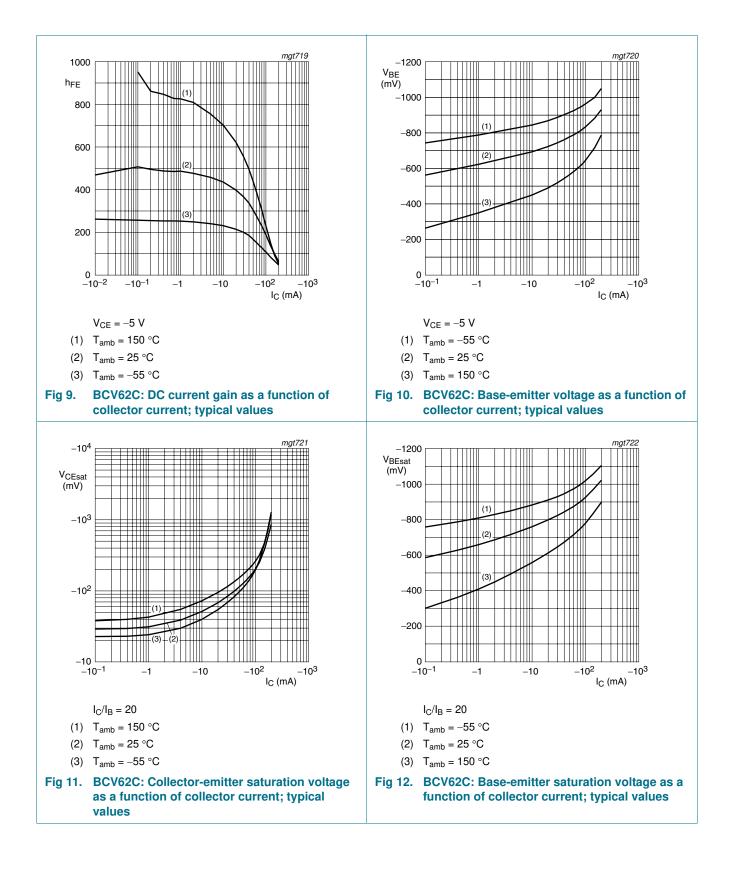


#### **NXP Semiconductors**

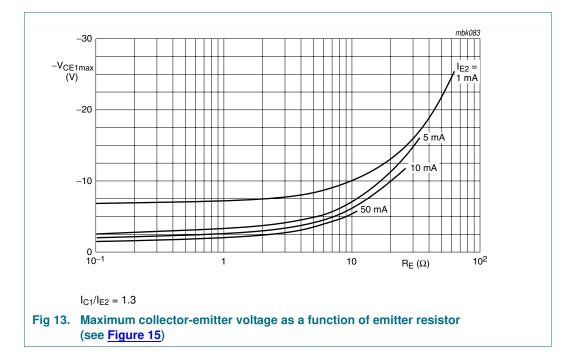
#### PNP general-purpose double transistors



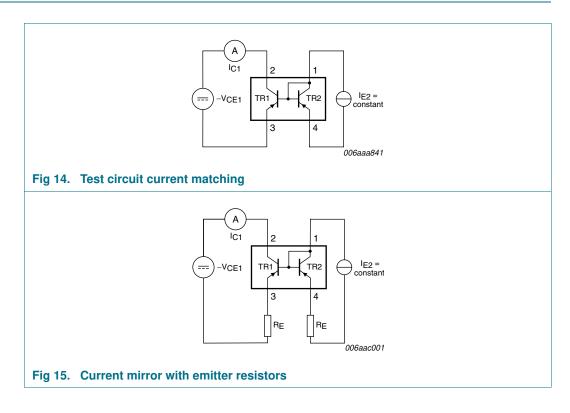
#### PNP general-purpose double transistors



#### PNP general-purpose double transistors



# 8. Test information

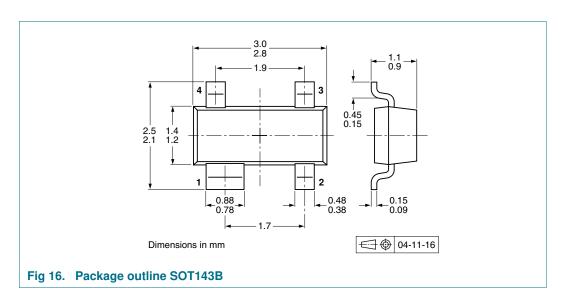


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#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 9. Package outline



## **10. Packing information**

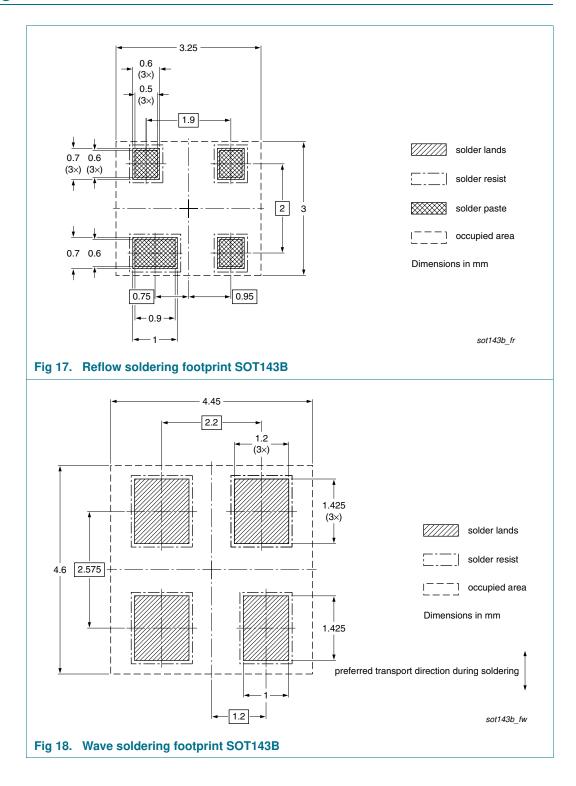
#### Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Package	Description		Packing quantity		
		300	0 100	00	
SOT143B	SOT143B 4 mm pitch, 8 mm tape and reel	-215	-215 -235		
	5		300	3000 1000	

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

## 11. Soldering



Supersedes

Change notice

# 12. Revision history

Table 10.	<b>Revision hist</b>	ory	
Documen	t ID	Release date	Data sheet status
BCV62 v A		20100726	Product data choot

BCV62 v.4	20100726	Product data sheet	- BCV62_3		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> </ul>				
	<ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>				
	<u>Section 1 "Product profile"</u> : amended				
	<u>Section 3 "Ordering information"</u> : added				
	<u>Section 4 "Marking"</u> : updated				
	• <u>Figure 1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 11</u> and <u>12</u> : added				
	<u>Section 8 "Test information"</u> : added				
	<ul> <li>Figure 16: superseded by minimized package outline drawing</li> </ul>				
	<u>Section 10 "Packing information"</u> : added				
	<u>Section 11 "Soldering</u> ": added				
	<u>Section 13 "Legal information"</u> : updated				
BCV62_3	19990408	Product specification	- BCV62_CNV_2		
BCV62_CNV_2	19970618	Product specification			

# 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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BCV62

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#### PNP general-purpose double transistors

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